

## **Dual Power Schottky Diode**

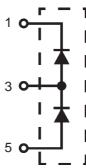
in ISOPLUS i4-PAC™

 $T_C = 25^{\circ}C$ 

P<sub>tot</sub>

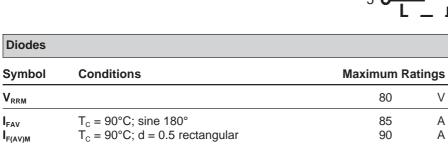
FSS 100-008A

= 80 V= 0.9 VI<sub>F(AV)M</sub> = 90 A



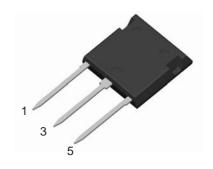
100

W



(per diode)

Symbol	Conditions	Characteristic Values (T <sub>VJ</sub> = 25°C, unless otherwise specified) min.   typ.   max.		
V <sub>F</sub>	I <sub>F</sub> = 75 A; T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 125°C		0.9 0.8	1.0 V
I <sub>R</sub>	$V_R = V_{RRM}, T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$		2.5	2 mA mA
R <sub>thJC</sub>	(per diode)		1	1.4 K/W



## **Features**

- · Schottky diodes
- very low forward voltage
- extremely fast switching
- blocking capability optimized for elevated temperature
- ISOPLUS i4-PAC<sup>™</sup> package
- DCB isolated back surface
- enlarged creepage towards heatsink
- application friendly pinout
- low inductive current path
- high reliability
- industry standard outline

## **Applications**

- for use in
- automotive drives and converters
- hand held tools
- low voltage power supplies
- battery chargers
- solar converters
- operating
- as free wheeling diode of choppers for supply of motors or transformers
- as high frequency secondary rectifier
- anti paralleled to MOSFETs complementing their intrinsic body diode

**Recommended replacement: DSSS 35-008AR** 

Data according to IEC 60747 and refer to a single diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions.



Component						
Symbol	Conditions	Maximum Ratings				
T <sub>vJ</sub> T <sub>stg</sub>		-55+175 -55+125	°C			
V <sub>ISOL</sub>	I <sub>ISOL</sub> ≤ 1 mA; 50/60 Hz	2500	V~			
F <sub>c</sub>	mounting force with clip	20120	N			

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
$C_P$	coupling capacity between shorted pins and mounting tab in the case		40	pF
$d_s, d_{\Delta}$	pin - pin	5.5		mm
$d_{s}, d_{A}$ $d_{s}, d_{A}$	pin - backside metal	5.5		mm
R <sub>thCH</sub>	with heatsink compound		0.15	K/W
Weight			9	g

